NSN 5961-01-310-1999

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View Online at https://aerobasegroup.com/nsn/5961-01-310-1999 **Inclosure Material:** Metal **Overall Length:** 8.327 inches **Function For Which Designed:** Rectifier **End Application:** Radio terminal digital troposcatter (an/trc-170). Singars system family. Communications program, combat theater (tri-tac)478i. **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 750.0 repetitive peak reverse voltage and 750.0 nonrepetitive peak reverse voltage and 750.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 110.00 amperes forward current, total rms nanoamperes **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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